

Vishay Semiconductors

Small Signal Switching Diode, High Voltage



FEATURES

- Silicon epitaxial planar diode
- · Fast switching diode, especially suited for applications requiring high voltage capability
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial



- grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

MECHANICAL DATA

Case: SOD-323 Weight: approx. 4.3 mg

Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE				
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS
GSD2004WS	GSD2004WS-E3-08 or GSD2004WS-E3-18	Single diede	В6	Tape and reel
	GSD2004WS-HE3-08 or GSD2004WS-HE3-18	Single diode		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Continuous reverse voltage		V_R	240	V	
Repetitive peak reverse voltage		V _{RRM}	300	V	
Forward current (continuous)		I _F	225	mA	
Peak repetitive forward current		I _{FRM}	625	mA	
Non repetitive peak forward as went	t _p = 1 μs	I _{FSM}	4	A	
Non-repetitive peak forward current	t _p = 1 s	I _{FSM}	1	Α	
Power dissipation (1)		P _{tot}	200	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Typical thermal resistance junction to ambient air (1)		R _{thJA}	650	K/W
Junction temperature		Tj	150	°C
Storage temperature range		T _{stg}	-65 to +150	°C
Operating temperature range		T _{op}	-55 to +150	°C

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	I _R = 100 μA	V_{BR}	300			V
Leakage current	V _R = 240 V	I _R			100	nA
	$V_R = 240 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I _R			100	μΑ
Forward voltage	I _F = 20 mA	V _F		0.83	0.87	V
	I _F = 100 mA	V _F			1	V
Diode capacitance	$V_F = V_R = 0$, $f = 1$ MHz	C _D			5	pF
Reverse recovery time	$I_F = I_R = 30$ mA, $i_R = 3$ mA, $R_L = 100 \Omega$	t _{rr}			50	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

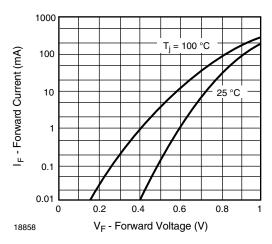


Fig. 1 - Forward Current vs. Forward Voltage

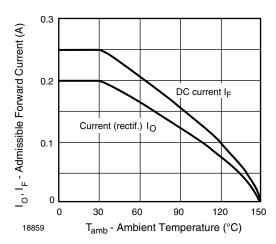


Fig. 2 - Admissible Forward Current vs. Ambient Temperature

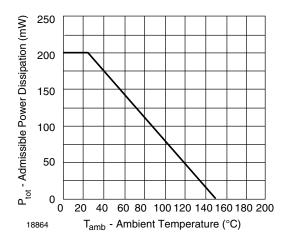


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

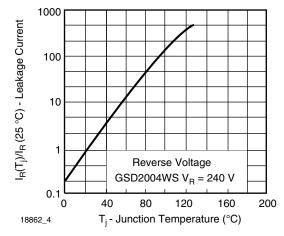


Fig. 4 - Leakage Current vs. Junction Temperature



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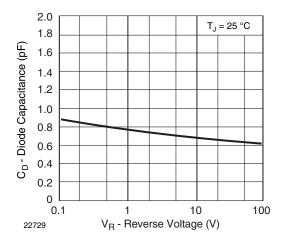
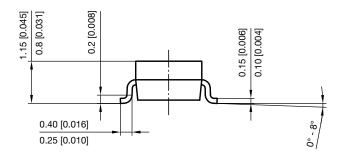
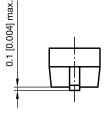
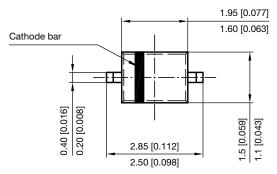


Fig. 5 - Capacitance vs. Reverse Voltage

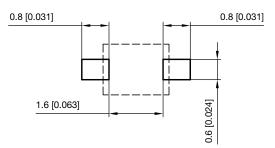
PACKAGE DIMENSIONS in millimeters (inches): SOD-323







Footprint recommendation:



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